REMARKS

Claims 17–23, 25, 46–49 and 51–59 are pending in the present application.

Claims 17–23, 25, 58 and 59 were withdrawn from consideration in the parent application. Reconsideration of the restriction requirement within the parent application is respectfully requested. As previously noted, the claims as amended within the application provide no basis for differentiating the process of making and the product made due to alleged patentable novelty between deposition of oxide and thermal growth of oxide. Independent claims 17 and 25 each recite, generically, forming the gate oxide layer, which encompasses both deposition and thermal growth.

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If any issues arise, or if the Examiner has any suggestions for expediting allowance of this Application, the Applicant respectfully invites the Examiner to contact the undersigned at the telephone number indicated below or at *dvenglarik@munckbutrus.com*.

The Commissioner is hereby authorized to charge any additional fees connected with this communication or credit any overpayment to Deposit Account No. 50-0208.

Respectfully submitted,

MUNCK BUTRUS, P.C.

Date: 5-8-06

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